

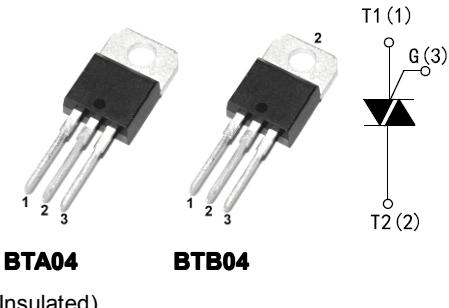
BTA04 / BTB04

4A TRIACS

General Description

- Package: TO-220T
- High current density due to double mesa technology, SIPOS and Glass passivation . BTA04/ BTB04 series triacs is Suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or phase control operation light dimmers, motor speed controllers.
- BTA04/ BTB04 series are 3 Quadrants triacs, They are specially recommended for use on inductive loads.

DRAWING



Absolute Maximum Ratings

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40 to +150	°C
Operating junction temperature range		T _j	-40 to + 125	°C
Repetitive Peak OFF-state Voltage	T _j =25°C	V _{DRM}	800	V
Repetitive Peak Reverse Voltage	T _j =25°C	V _{RRM}	800	V
Non repetitive surge peak off-state voltage		V _{DSM}	800	V
Non repetitive peak reverse voltage	T _p =10ms, T _j =25°C	V _{RSM}	800	V
RMS on-state current(full sine wave)	T _C =107°C	I _T (RMS)	4	A
Non repetitive surge peak on-state current(full cycle,T _j =25°C)	f=60Hz,t=16.7ms	ITSM	27	A
	f=50Hz,t=20ms		25	
I ² t Value for fusing	T _p =10ms	I ² t	3.1	A ² s
Critical rate of rise of on-state current I _G =2*I _{GT} ,t _r ≤100ns,f=120Hz,T _j =125°C	I - II - III IV	dI/dt	50 20	A/us
Peak gate current(tp=20us,T _j =125°C)		I _{GM}	2	A
Peak gate power dissipation(tp=20us,T _j =125°C)		P _{GM}	5	W
Average gate power dissipation(T _j =125°C)		P _{G(AV)}	0.5	W

Electrical Characteristics ($T_j=25^\circ\text{C}$,unless otherwise specified)

Symbol	Test Condition	Quadrant		Limit				Unit
				D	E	F	G	
I_{GT}	$V_D=12\text{V}, R_L=33\Omega$	I - II - III IV	MAX	5	10	25	50	mA
V_{GT}				10	25	70	100	
V_{GD}	$V_D=V_{DRM}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$	ALL	MIN	0.2				V
I_L	$I_G=1.2I_{GT}$	I - III - IV	MAX	15	30	40	60	mA
		II	MAX	20	40	60	90	mA
I_H	$I_T=100\text{mA}$		MAX	10	25	30	60	mA
Dv/dt	$VD=67\%V_{DRM}$ gate open $TJ=125^\circ\text{C}$		MIN	5	10	50	200	V/us
$(Dv/dt)_c$	$(dl/dt)_c=1.1\text{A/ms}$ $Tj=125^\circ\text{C}$		MIN	1	2	5	10	V/us

Static Characteristics

Symbol	Parameter	Value	Unit
$R_{th}(J-C)$	Junction to case(AC)	3.7	°C/W

Thermal Resistances

Symbol	Parameter	Value(MAX)	Unit
V_{TM}	$ITM=5\text{A}, tp=380\text{us}$	$T_j=25^\circ\text{C}$	1.7
I_{DRM}	$VD=V_{DRM}$ $VR=V_{RRM}$	$T_j=25^\circ\text{C}$	5
I_{RRM}		$T_j=125^\circ\text{C}$	1